

3.0Amp Surface Mount General Purpose Rectifiers

S3A~S3M

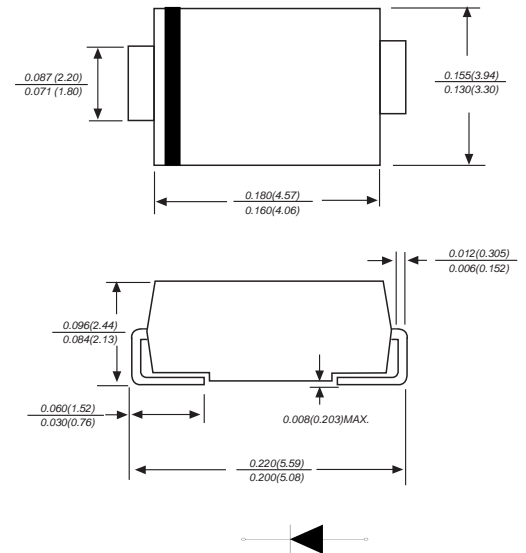
Features

- ◆ The plastic package carries Underwriters Laboratory Flammability Classification 94V-0
- ◆ For surface mounted applications
- ◆ Low reverse leakage
- ◆ Built-in strain relief, ideal for automated placement
- ◆ High forward surge current capability
- ◆ High temperature soldering guaranteed:
250°C/10 seconds at terminals
- ◆ Glass passivated chip junction

Mechanical Data

Case: JEDEC DO-214AA molded plastic body over passivated chip
Terminals: Solder plated, solderable per MIL-STD-750, Method 2026
Polarity: Color band denotes cathode end
Mounting Position: Any
Weight : 0.003 ounce, 0.093 grams

DO-214AA/SMB



Dimensions in inches and (millimeters)

Maximum Ratings And Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified. Single phase half-wave 60Hz, resistive or inductive load, for capacitive load current derate by 20%.

| | SYMBOLS | S3A | S3B | S3D | S3G | S3J | S3K | S3M | UNITS |
|---|-----------------|---------------|-----|-----|-----|-----|-----|------|--------------------|
| Maximum repetitive peak reverse voltage | V_{RRM} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum RMS voltage | V_{RMS} | 35 | 70 | 140 | 280 | 420 | 560 | 700 | VOLTS |
| Maximum DC blocking voltage | V_{DC} | 50 | 100 | 200 | 400 | 600 | 800 | 1000 | VOLTS |
| Maximum average forward rectified current at $T_L=75^\circ\text{C}$ | $I_{(AV)}$ | 3.0 | | | | | | | Amps |
| Peak forward surge current 8.3ms single half sine-wave superimposed on rated load (JEDEC Method) | I_{FSM} | 100.0 | | | | | | | Amps |
| Maximum instantaneous forward voltage at 3.0A | V_F | 1.15 | | | | | | | Volts |
| Maximum DC reverse current $T_A=25^\circ\text{C}$ at rated DC blocking voltage $T_A=100^\circ\text{C}$ | I_R | 10.0 100.0 | | | | | | | μA |
| Typical junction capacitance (NOTE 1) | C_J | 60.0 | | | | | | | pF |
| Typical thermal resistance (NOTE 2) | $R_{\theta JA}$ | 47.0 | | | | | | | $^\circ\text{C/W}$ |
| Operating junction and storage temperature range | T_J, T_{STG} | -65 to +150 | | | | | | | $^\circ\text{C}$ |

Note:1. Measured at 1MHz and applied reverse voltage of 4.0V D.C.

2. P.C.B. mounted with 0.2x0.2" (5.0x5.0mm) copper pad areas

Ratings And Characteristic Curves

S3A THRU S3M

FIG. 1- FORWARD CURRENT DERATING CURVE

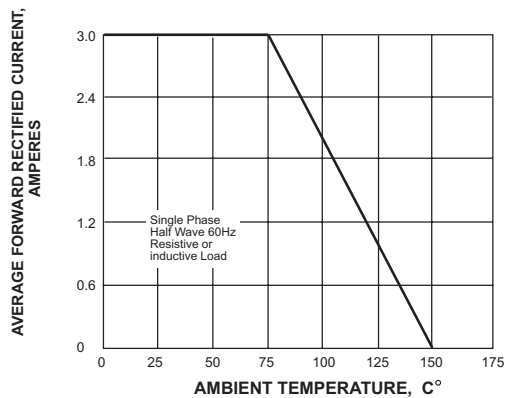


FIG. 2-MAXIMUM NON-REPETITIVE PEAK FORWARD SURGE CURRENT

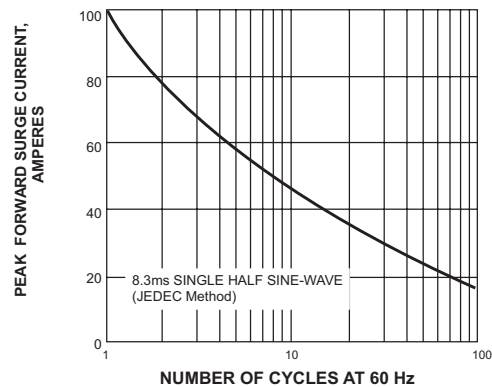


FIG. 3-TYPICAL INSTANTANEOUS FORWARD CHARACTERISTICS

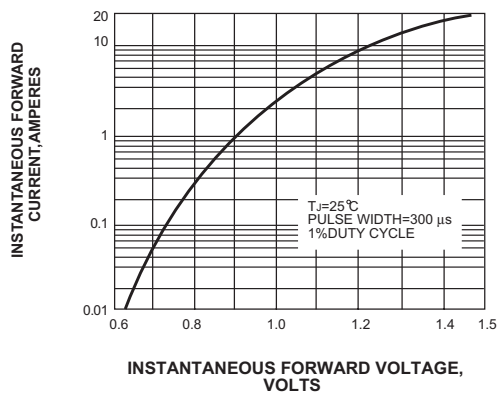


FIG. 4-TYPICAL REVERSE CHARACTERISTICS

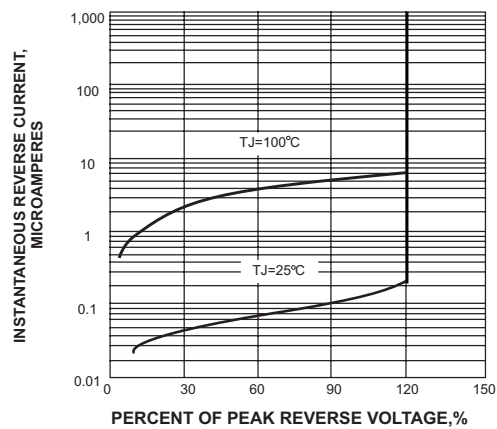


FIG. 5-TYPICAL JUNCTION CAPACITANCE

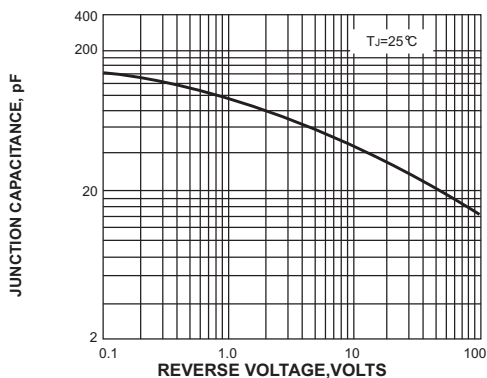


FIG. 6-TYPICAL TRANSIENT THERMAL IMPEDANCE

